

KSC5802

High Voltage Color Display Horizontal Deflection Output (No Damper Diode)

High Breakdown Voltage: BV_{CBO}=1500V
 High Speed Switching: t_F=0.1µs (Typ.)

• Wide S.O.A

• For C-Monitor(69KHz)



NPN Triple Diffused Planar Silicon Transistor

Absolute Maximum Ratings $\rm T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	1500	V
V_{CEO}	Collector-Emitter Voltage	800	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current (DC)	10	Α
I _{CP}	Collector Current (Pulse)	30	Α
P _C	Collector Dissipation (T _C =25°C)	60	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CES}	Collector Cut-off Current	V _{BE} =0, V _{CE} = 1400V			1	mA
I _{CBO}	Collector Cut-off Current	$V_{CB} = 800V, I_{E} = 0$			10	uA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 4V, I_{C} = 0$			1	mA
h _{FE1} h _{FE2}	DC Current Gain	$V_{CE} = 5V, I_{C} = 1A$ $V_{CE} = 5V, I_{C} = 6A$	15 7		48 10	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 6A, I_B = 1.5A$			3	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 6A, I_B = 1.5A$			1.5	V
t _F	Fall Time	$V_{CC} = 200V, I_C = 6A$ $I_{B1} = 1.2A, I_{B2} = -2.4A$ $R_L = 33.3\Omega$		0.1	0.3	μs

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Typical Characteristics

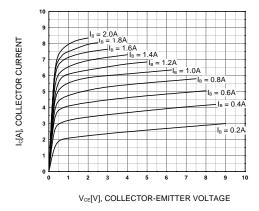


Figure 1. Static Characteristic

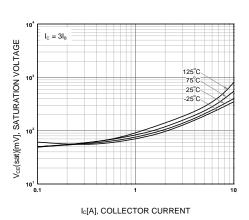


Figure 3. Collector-Emitter Saturation Voltage 1

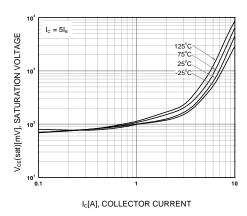


Figure 5. Collector-Emitter Saturation Voltage 2

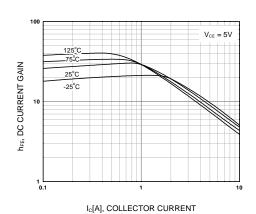


Figure 2. DC current Gain

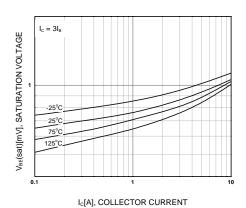


Figure 4. Base-Emitter Saturation Voltage 1

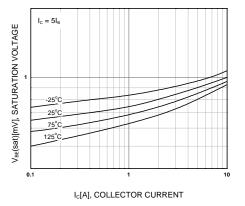


Figure 6. Base-Emitter Saturation Voltage 2

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Typical Characteristics (Continued)

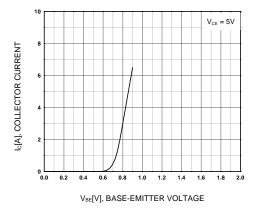
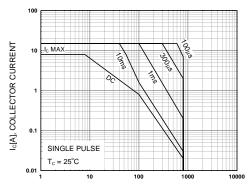


Figure 7. Base-Emitter On Voltage



 $V_{\text{CE}}[V], \, \text{COLLECTOR-EMITTER} \, \, \text{VOLTAGE}$

Figure 8. Safe Operating Area

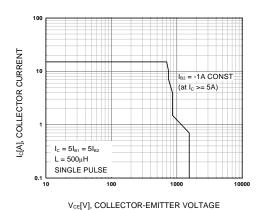


Figure 9. Reverse Safe operating Area

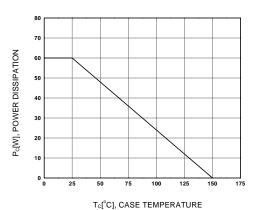
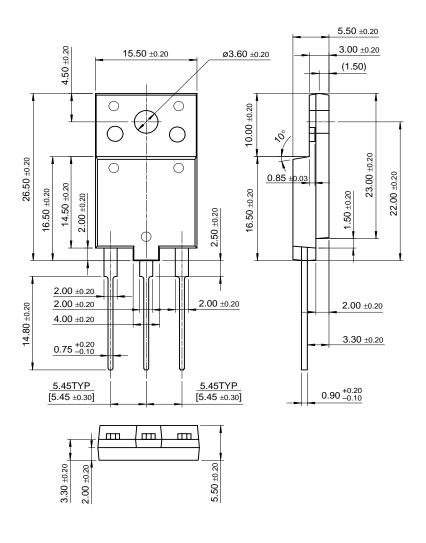


Figure 10. Power Derating

Package Demensions

TO-3PF



Dimensions in Millimeters

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